CNB1301 (ON2171)

Reflective Photosensor

For contactless SW and object detection

Overview

CNB1301 is a reflective photosensor consisting of a small, thin reflective photosensor (CNB1302) to which a plastic lens is attached to increase the focal distance from 0.8 mm to 2.5 mm.

Features

- Small size, light weight: 5 mm × 4.5 mm (height: 4.0 mm)
- Focal distance: 2.5 mm
- Visible light cutoff resin is used

Applications

- Copier
- Printers
- Fax
- Cassette deck

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter		Symbol	Rating	Unit	
Input (Light emitting diode)	Power dissipation *1	P _D	75	mW	
	Forward current	I _F	50	mA	
	Reverse voltage	V _R	S 3	V	
Output (Photo transistor)	Collector-emitter voltage (Base open)	V _{CEO}	30	V	
	Emitter-collector voltage (Base open)	V _{ECO}	19 ¹⁵ 85	N K SC	
	Collector current	I _C	20	mA	
	Collector power dissipation *2	P _C	50 8	mW	
Operating ambient temperature		T _{opr}	-25 to +75	°C	
Storage temperature		T _{stg}	-30 to +80	°C	

Note) *1: Input power derating ratio is 1.36 mW/°C at $T_a \geq 25^\circ C$

*2: Output power derating ratio is 0.91 mW/°C at $T_a \ge 25^{\circ}C$

Note) The part number in the parenthesis shows conventional part number.

Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Input characteristics	Reverse current	I _R	$V_R = 3 V$			10	μΑ
	Forward voltage	V _F	$I_F = 50 \text{ mA}$		1.3	1.5	V
Output characteristics	Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 V$			200	nA
Transfer characteristics	Collector current ratio *1	I _C	$V_{CC} = 5 \text{ V}, I_F = 10 \text{ mA},$ $R_L = 100 \Omega, d = 4 \text{ mm}$	0.8		5.2	mA
	Drain current *2	I _D	$V_{CC} = 5 \text{ V}, I_F = 10 \text{ mA},$ $R_L = 100 \Omega$			40	μΑ
	Collector-emitter saturation voltage	V _{CE(sat)}	$I_{\rm F} = 20 \text{ mA}, I_{\rm C} = 0.1 \text{ mA}$			0.5	V
	Rise time *3	t _r	$V_{\rm CC} = 5 \text{ V}, I_{\rm C} = 0.1 \text{ mA},$		20		μs
	Fall time *3	t _f	$R_L = 100 \Omega$		20	5.	μs

Note) 1. Input and output are practiced by electricity.

- 2. This device is designed by disregarding radiation.
- 3. *1: Output current measurement circuit

$$\begin{array}{c} & I_{\rm F} \\ & \downarrow I_{\rm C} \\ & I_{\rm C$$



*2: No reflector and dark condition.





 t_r : Time required for the collector current to increase from 10% to 90% of its final value

 t_f : Time required for the collector current to decrease from 90% to 10% of its initial value

Panasonic



Package (Unit: mm)

LSSLRR4S0001





- Pin name
 - 1: Anode
 - 2: Cathode
 - 3: Emitter
 - 4: Collector

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